REV.

01 DATE 11-14-73

PAGE 1 of 16

R

TEST PROCEDURE - T7411 AND T7411-402 CATHODE RAY TUBE

1.0 FRONT PANEL CONTROLS

Turn intensity CCW Grid bias CCW Gun to normal Select Non-Store Mode Connect line raster generator Turn on P-690 Test Unit

Vert Pos - GND TIME BASE -AUTO-AC-1101 TIME B. B AAPL. INTENS - CCW Eco for con off.

SPECIFICATION LIMIT

2.0 CUTOFF, CATHODE CURRENT, BEAM CURRENT, FOCUS UNIFORMITY, GEOMETRY, ALIGNMENT & SENSITIVITIES:

- Depress E_{CO} button. Increase intensity so a spot is just visible.
- Adjust spot for best focus and astigmatism at the tube center.
- 2.3 Switch to halftone and increase/decrease operating level until some background is observed.
- 2.4 Turn intensity CCW and increase grid bias until a spot begins to store. Reduce grid bias so that the spot will no longer store. Record as cutoff voltage on test form. (May need to erase to determine if spot is storing.)
- 2.5 Check electrical center: (Reference to graticule line.)
- 2.6 Switch gun to gearshift. Check that tube is cutoff. If not, readjust bias so that it will no longer store.
 - 2.7 Return to conventional mode and gun to normal.
 - 2.8 Set intensity for 50V drive. Center vertically and and measure beam current. Record on test form.
 - Switch gun to gearshift and note that current is greater than normal mode current. If not, notify LEAD OPERATOR. Switch gun back to normal mode.

Selector to H7 IK-AUT-AC-OND. U-Roselin A.C 75 - 105 VDC

±2.5 Minor Div.

25µA Min.

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REV. 01

DATE 11-14-73

PAGE 2 of 16

R 2.0 CUTOFF, CATHODE CURRENT, BEAM CURRENT, FOCUS UNIFORMITY, GEOMETRY, ALIGNMENT & SENSITIVITIES: (Cont.) SPECIFICATION LIMIT

2.10 Measure cathode current as set-up in Sec.2.8 and record as I_k @ 50V drive on test form.

Vco			,	I_k		
75	_	79		.48	mA	Min.
80	•	84		.44	mA	Min.
85		89		.40	mA	Min.
90	-	94		.38	mA	Min.
95	-	99		.34	mA	Min.
100	-	105		.32	mA	Min.

@ AMP .- OC-EXT

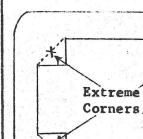
2.11 Set intensity for a I_k reading of .4ma and measure beam current. Record as I_b @ I_k = .4ma.

26µA Min.

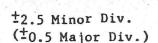
2.12 Switch gun to gearshift. Note if beam current is greater than recorded value. If not, notify LEAD OPERATOR. Switch gun back to normal.

2.13 Reduce intensity and position spot to center of graticule. Measure the major axis of the smallest focused spot and compare with the major axis when the spot is positioned to corner extremes (See Fig.)

≤ 2.6.:1



- 2.14 Select horizontal lines. Set time base to $10\mu S/Div$. Slowly increase intensity until lines are visible. Check rotational alignment, using center graticule line.
- 2.15 Set geometry for straight horizontal lines.
 Switch to vertical lines. NOTE straightness of vertical lines. If not within specifications, adjust vertical lines until within specification. Check horizontal lines for straightness.
- 2.16 Select vertical lines. Using center graticule line, check orthogonality of trace (horizontal lines should be aligned).



- 0.5 Minor Div. Total
- ±0.7 Minor Div. (± 1°)

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8-2019 NO.

REV. 01

DATE 11-14-73

PAGE 3 of 16

2.0 CUTOFF, CATHODE CURRENT, BEAM CURRENT, FOCUS UNIFORMITY, GEOMETRY, ALIGNMENT & SENSITIVITIES: (Cont.)

Ground vertical input. Switch horizontal to Amplifier with external trigger source (should have spot).

Depress Horizontal Button on P.T.U. meter and position horizontally to graticule extremes, noting meter readings. Add absolute value of two readings.

Depress vertical button and P.T.U. meter and position vertically to graticule extremes, noting meter readings. Add absolute value of, two readings.

3.0 HALFTONE SETUP NORM-EXT--10 X1 4C Selection @ HT

- Select halftone mode and erase. Measure flood 3.1 gun cathode current.
- Set operating level to Q volts and prep voltage fully CCW.
- Erase target and adjust operating level until target just starts to drop from saturation after erasure. Increase this operating level by three (3) volts and record on data form as halftone operating point. Just get ned for
- Measure luminance at the five (5) points shown; 3.4 record the average reading as saturation luminance.

PREP OL Voltage until a small area of the target just drops from saturation. Record . Lower operating level and erase; continue to do so until first area just dark (1 Div. Sq.). Record as first dark O.L.

Vary operating level until the full 8 x 10 3.6 quality area is dark after erasure. Record this O.L. as last dark.

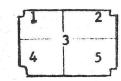
SPECIFICATION LIMIT

99 - 117V Total (10.8 ±.9 V/Div.)

28 - 32.8V Total $(3.8 \pm .3V/Div)$

.22 mA Min.

≥100 fL.



REV. 01

DATE 11-14-73

PAGE 4 of 16

4.0 HALFTONE WRITING SPEED & TARGET DEFECTS

4.1 Set Drive for 50 volts. set gud make & Earine

4.2 Connect low-frequency sine wave generator to vertical, set for 100KHz, and adjust gain for 6.4 Div.

- 4.3 Adjust horizontal for a minimum display of seven (7) complete cycles.
- 4.4 Store the sine wave in different locations of the

 6 x 8 Div. quality area to determine the limiting

 areas for writing speed and view time.

NOTE: Writing speed may be limited by some area other than the area which is darkest.

4.5 Position the midpoint of the sine wave on the slowest area.

4.6 A. WRITING SPEED:

Vary the frequency and operating level until the trace just stores or until trace breaks .040".

Measure time for the display to fade-up (signal no longer visible above background). If the view time (fade-up time) is different from 15 seconds, readjust the operating level and frequency until the view time is just 15 seconds.

Record as 15 sec. writing speed.

~ oplevel control

4.7 A. TARGET DEFECTS: (Bright Spots)

Erase the target. Measure questionable bright spot defects. If defects out of specification, set frequency to 25 KHz. Erase and write target, varying O.P. level until written trace is just visible. Erase and measure defects. If above limits, reject.

- 4.8 Switch gun to gearshift. Repeat Sec.4.6.A for gearshift writing speed with 3.2 Div. Sine wave on center 4 x 5 Div. area. Use about lMHz initially. Switch gun to normal mode.
- 4.9 Repeat Sec.4.6.A, using a view time of one (1) minute.
- 4.10 TARGET DEFECTS: (Dark Spots)

Increase the operating level until the screen is saturated. Measure questionable dark defects.

SPECIFICATION LIMIT

0.5 Div/ μ s Min.

See P.S.8-2011, Table I

1.5 Div/µs Min. Record

Record Data - Q.A. Only

See P.S.8-2011, Table I

Immion] Set 40 Ma Ib - HT 7B70 (Time BASE) 10KB = Be sure red CONNECT MEGAH SINEW gen to Vert SET TO ROOMHE Push Top 3 Buttons - P-P., Ac, Into No Conver - XI Check to see that it Laesit over-san HORI'Z, - if it does - shorten uf screet drives adjust - on side whing Theswitch - blue screw - of CRT Mond. Scope S.S. AC. LING IT hostofeat al. 1 or 2 see NORM XFR 5. HTYER - triggered - (bleer lites and engo HTXFR EMISSION RETURN VT TO VT found for W.S. 7. Erase 9 TO S.M - (HS in HTXFREm.) - To start trace 11. single - grat on 7B70 -12, Should have a spike 13. Measure amp. 7 spike 111 plug, men scope must be an 5 ml. return to normal + off

REV. 01

DATE 11-14-73

5 of 16 PAGE

5.0 TARGET SENSITIVITY & SECONDARY EMISSION FOR STORAGE MESH

- Set Ib = 40µA with gun in normal mode. Focus 5.1 trace.
- 5.2 Select 50KHz sinewave and set for 6.4 Div. Select halftone mode and set operating level to value recorded as last dark (Sec. 3.6).
- Erase. Confirm that at last dark condition. I found adjust Decrease operating level one (1) volt below the last dark.
- 5.4 Erase. Single sweep sinewave over last dark area (midpoint of sinewave over area). Vary frequency and erase until trace is just visible. Record 20X as target sensitivity for storage mesh.

red button in Set timebase to 10µs/Div, and 1X. Select 100MHz sinewave. Set for 5 Div. amplitude. Switch to single sweep and external trigger. & TRIG. INT.

5.6 Erase. Select storage mesh position on secondary emission selector. Depress internal trigger noting amplitude at spike on output signal. Record value in millivolts. S-AC-INT

SPECIFICATION LIMIT

Sample Data & Engineering Test only

- also return of To lust dark VI

TE HOICIE IS OVEY enger of grand while

> Sample Data & Engineering Test Only

6.0 HALFTONE RESOLUTION

- Adjust intensity for 1µA beam current. if the won thouh increase it a lit, Focts
- 6.2 Select vertical lines and non-store mode. Focus trace. (Switch between vertical and horizontal line looking for best trace in both directions.)
- 6.3 Adjust vertical gain for 8 Div. Select Halftone Mode. Erase target for target condition corresponding to just dark.
- on MONO 6.4 Adjust line speed so that every line is written above just visible condition. Shrink spacing between lines increasing number of lines until lines are just discernible over 8 x 10 Div. area.

(intem DIV) Count the number of vertical lines stored over two (2) divisions. Record 1/2 of this number as resolution.

uf MON. Scope T. Base contral. as you Store a crase vary T. Base central lines are just visible in 8 × 10 then vary T.B. on P. Supply unit until lines are just descernable lines are just descernable over 8VW

Res -Lua CONNECT Res, Lean to Vert! AC, INT. P.P. NON-ST. ON MUN. Scope Auto, Ext. Ac. 2 msec sweep otherteme base 2 mee. should have some VT.

10 line/Div Min.

LINES- 6-8

Focus

REV. 01

DATE 11-14-73

PAGE 6 of 16

7.0 VARIABLE PERSISTENCE UNIFORMITY

7.1 Set persistence duty factor to 3%.

7.2 Inhibit persistence pulses. Erase for just dark and write total 8 x 10 divisions to saturation (increase drive and single sweep).

- 7.3 Initiate pulsing and note first and last areas to decay.
- 7.4 Repeat Sec.7.2. Place luminance probe at first area to decay away as noted in Sec.7.3. Initiate pulsing. Record decay time as first decay.
- 7.5 Repeat Sec. 7.4 for last area to decay. Record.
- 7.6 Divide decay time of Sec.7.5 by Sec.7.4.

 $\leq 3:1$

R 8.0 RESIDUAL IMAGE - STORAGE MESH

- 8.1 Set beam current for 40µA in gearshift. Focus trace. Select single sweep.
- 8.2 Select halftone. Erase. Set operating level for just dark condition.
- 8.3 Select non-store mode. Set timebase at 10us/Div. and ground vertical input signal.
- 8.4 Switch timebase to Auto and Ext. Trigger. Let horizontal line run for one (1) minute, then switch to single sweep. Turn intansity full CCW,
- 8.5 Erase twice. Record difference in operating levels needed to make the area written and the adjacent area dark. If area written blacker than background, then record as negative.

R 9.0 HALFTONE TRANSFER WRITING SPEED

- 9.1 Select halftone fast mode. Set operating level for near all dark condition (i.e., some visible background. Turn intensity full CCW. Preset Vp for five (5V) volts and Vt for two (2V) volts.
- 9.2 Set timebase to single sweep and internal triggering. Erase. Note condition of display.

SPECIFICATION LIMIT

NORM, AC, EXC NORM, AC, EXC HTXER LIVES

REV. 01

DATE 11-14-73

PAGE 7 of 16

9.0 HALFTONE TRANSFER WRITING SPEED (Cont.)

9.3 Erase and wait for fifteen (15 Sec.) seconds.
Trigger sweep. NOTE condition of background.
If different than that of Sec.9.2 or immediate
transfer, then need to change stability setting.
If background higher after fifteen (15 sec.) seconds,
then increase stability voltage (i.e., stability
knob CW). If background lower, then decrease stability voltage.

- 9.4 Repeat Sec.9.3 until display appears nearly the same.
 Now check for 60 Sec.by erase and waiting 60 Sec.
 Adjust stability until display after 60 Sec. wait
 is same as initial transfer.
- 9.5 Set drive to fifty (50V.) volts. Connect 7.5MHz sinewave to input. Adjust for 6.4 Div. amplitude. Focus trace in Non-Store.
- 9.6 Choose halftone fast mode. Erase and note condition of written signal. Adjust Vt after each transfer until background begins to change.
- 9.7 Erase and wait fifteen (15 Sec.) seconds. Trigger sweep and note condition of transferred signal and background. If background or signal is transferred better after 15 second wait, then decrease V_p. If background or signal is transferred worse after 15 seconds waiting, then increase V_p. Readjust V_t.
- 9.8 Repeat Sec.9.7 until condition at initial transfer and fifteen (15 Sec.) second stability check are nearly the same.
- 9.9 Repeat Sec.9.7 through Sec.9.8 for stability check time of sixty (60 Sec.) seconds.
- 9.10 Recheck front mesh stability per Sec.9.3 through Sec.9.4.
- 9.11 Erase. Record Vp , Vt, and stability level as hi-speed prep, XFR voltage and hold level-storage mesh, respectively.
- 9.12 Erase. Measure viewtime of display with 7.5MHz 6.4 Div sinewave positioned over slowest area and written to just visible or .040 break in transferred trace. Record viewtime as viewtime at 150 Div/μs.

SPECIFICATION LIMIT

a chest X-ray

≥15 Sec.

H	HTKER SENSITIUTY
	Ib = 40Ma = 11 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
ļ.	En de de la constant
2,	Focused LEAUE MHZ SINE at W.S setting used
3,	LEAUE / LAZINO
	TO get HTXFR W.S.
4,	vary O.L UNTIL ONE SMALL AREA
	HAS JUST A IIII
5	To ally That area.
	Landard VT WATTI
41	Lower WAtch VT on DVM)
_	Then Lowey VT I love) volt. (eg. magative) Then Lowey VT I love) volt. (eg. magative) Below whereit fust stores - (it will need go to -1.4
7,	Below where it fust stores [INITIA] - 4
81	Now VARY FREG - (it will need go to -1.4)
	To the account of reduce Tim click
	(usually to or 1.6-3.6 range) also reduces Tim dais STAPE IN the same area
0	STORE IN the same area wis as forentially
7)	
	in step 6 about, record
	11/2 = 11 1/2 labord to
10	. Return VI to US VI used and Later
	sheet
	Do Emission same way
11.	Do emession Ht
	as done in HT-

REV.

01 DATE 11-14-73

PAGE 8 of 16

SPECIFICATION LIMIT

9.0 HALFTONE TRANSFER WRITING SPEED (Cont.)

9.13 Varying frequency determine transferred writing speed yielding fifteen (15 Sec.) seconds of viewtime. Record 20% frequency as writing speed at fifteen (15 Sec.) seconds without gearshift.

- 9.14 Switch gun to gearshift. Select 100MHz and set at 3.2 Div. Position over center 4 x 5 Div. looking for slowest writing area.
- 9.15 Adjust operating level until trace transfers to just visible and/or breaks in trace is less than .040". Measure viewtime. Record as viewtime for 1000 Div/us.

≥15 Sec.

10.0 TARGET SENSITIVITY & SECONDARY EMISSION FOR HI-SPEED MESH

10.1 Set Ib = 40µA with gun in normal mode. Focus the

at HIKFRUS 10.2 Select MMz 6.4 Div. sinewave. Select halftone fast mode. Set operating level for condition of barely visible background in a 1 Div. area on target. Decrease V, until trace is just transferring in that area.

- 10.3 Note V, reading. Decrease by one (1) volt.
- 10.4 Erase. Vary frequency until trace transferred to condition same as that of Sec. 10.2. Record 20X as sensitivity-hi-speed.
- 10.5 Set timebase to 10 µs/Div and 1X. Select 100MHz sinewave set for five (5) Div. amplitude. Switch to single sweep external trigger.
- 10.6 Erase. Select hi-speed mesh position on secondary emission selector. Depress internal trigger noting amplitude of spike on output signal. Record value in millivolts as Emission: hi-speed.

Sample Data & Engineering Test Only

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8-2019 NO.

01 REV.

11-14-73 DATE

9 of 16 PAGE

11.0 RESIDUAL IMAGE -HI-SPEED MESH

11.1 Set beam current for 40µA in gearshift. Focus the SPECIFICATION LIMIT trace. Select single sweep.

- 11.2 Select halftone fast. Erase. Set operating level for same background. Set Vp and Vt at values recorded in Sec.9.11.
- 11.3 Select non-store mode. Set timebase at 10µs/Div and ground vertical input. X / mag
- 11.4 Switch timebase to auto and set trigger. Allow horizontal line to run for one (1) minute. Switch to single sweep. Turn intensity full CCW. Set trigger at internal.
- LOWER FAST LEVEL CONTRUL 11.5 Erase and transfer twice. Record difference in Vt needed to suppress the transfer of the background and the residual.

12.0 BISTABLE OPERATING POINT

I b SWITCH UP NON-STORE

- 12.1 Set beam current to 15µa. AMPL. EXT.
- 12.2 Set focus and astigmatism on a 45° line from triangle.
- 12.3 Switch to bistable and erase.

8 XIOA 12.4 Single sweep a raster of lines and vary operating level erasing and rewriting until lines begin to break up. Raster must remain one (1) minute with no more than two (2) breaks .025" in a single line. Record as writing threshold.

- 12.5 Increase the operating level, erasing and rewriting until the trace begins to fade up. Trace should store one (1) minute without fading up over .025". Record as upper writing limit.
- 12.6 Set operation level midway between writing threshold and upper writing limit. Record as bistable operating point.

12.7 BISTABLE TARGET DEFECTS

- Erase the target and measure any questionable
- b. Fully write the bistable target and measure any questionable defects.

Sample Data & Engineering Test Only

pergin POS TRACE OFF Face VERTICALLY BS - erase men trace over tot & I line pu du wait Imin. UWL

> O.R. 10V Min. 0.P. 125V. Max.

See P.S.8-2011, Table I

BSXFR AFTER ALL Vis are set: Connect to MHZ sincu gen-Sitat sold Focus sinswave sit 6.4 die ampl. target Stability Ab = 120 VT = -1.5 Set MHZ S. wave gen. at 5 on 3.6 708 Store This speed to see if it writes -Vary V+ for = 5% transfer of I die (looks like)
I it doesn't write in most of 8x10raise Up - & vary VT. To maintain 5% Kfr.
may have to vary W.S. (slower or) to where it stores.
AC TNT S.S. AC INT went & 15 acc, HA+ S.S To store TRACE-ERASE If losts about as it die untally grbach to 5.5. Ac. Int, eruse a time for 60sec. Target has to look the same after 60 sec. as it kid initially. If it loses W.S. (breaks intrace) as less backgre is xfre up lower Vp (grown to Narm Ac, Est go thru a compete erase or , vary vi if needed If it feder up - raise up). Vy - curdles to Vp - stability (writes better)

REV. 01

DATE 11-14-73

PAGE 10 of 16

13.0 BISTABLE WRITING SPEED

- 13.1 Set Drive to 50 volts.
- 13.2 Connect a 5 KHz sinewave to vertical and adjust gain for a 6.4 Div. display.
- 13.3 Set focus and astigmatism on a 45° centered line.
- 13.4 Store a series of sinewaves to determine the slowest area of the 6 x 8 Div. quality area.

 (Adjust horizontal sweep for a minimum of one (1) cycle per Div.)
- 13.5 Position the center of the sinewave over the slowest writing area.
- 13.6 Erase and single sweep, varying the sinewave frequency until the slowest area just stores the trace with no breaks > .040", or is just visible above the background.
- 13.7 Record twenty (20) times the sinewave frequency as bistable writing speed.
- 13.8 Switch gum to gearshift. Repeat Sec.13.4 through 13.6 on center 4 x 5 Div. (.9cm/Div graticule) area using a 3.2 Div. amplitude sinewave.
- 13.9 Record ten (10) times the sinewave frequency as gearshift bistable writing speed.

R 14.0 BISTABLE TRANSFER WRITING SPEED

- 14.1 Connect 5MHz sinewave to vertical input. Switch gun to normal. Preset V_p for fifteen (15V) volts. Signal height to 6.4 Div.
- 14.2 Adjust V_{ϵ} for 5% fade-up of any single division.
- 14.3 Evaluate stability for fifteen (15) seconds by using timer and/or single sweep with external trigger. If there is a loss in writing speed and/or less background transferred, then decrease Vp.

 If more background transfer, then increase Vp.

SPECIFICATION LIMIT

40212 7870

Single sup De. 1NT.

NOTE: WS has to be hand-Stored- use SS, AC INT. S.S. Sivewave ITO determine U.S.

30 Div/ms Min.

100 Div/ms Min.

wrote @ ext . norm.

6 x 8 dir

7 any V - norm- Ac 5

p- 55 . INT & Eng o

REV. 01

DATE 11-14-73

PAGE 11 of 16

14.0 BISTABLE TRANSFER WRITING SPEED (Cont.)

- 14.4 Continue repeating Sec.14.3 until no detectable change in % background transferred or loss in writing speed.
- 14.5 Repeat Sec.14.3 and 14.4 for sixty (60 Sec.) seconds waiting period.
- 14.6 Record V_p and V_t as bistable hi-speed prep and XFR voltage, respectively.
- 14.7 Store sinewave in different areas of 6 x 8 Div. to determine writing speed by setting midpoint of sinewave at slowest writing area. Writing speed limit when there are no breaks in signal greater than .040 or trace is just visible above background.
- 14.8 Record 20X frequency as bistable transfer writing speed w/o gearshift.
- 14.9 Switch gun to gearshift. Repeat Sec.14.7 for center 4 x 5 Div. area using a 3.2 Div. amplitude sinewave. (May vary V_t to increase writing speed.)
- 14.10 Record 10X frequency as bistable transfer writing speed gearshifted.
- 14.11 Switch gun to normal.

SPECIFICATION LIMIT

≥ 30 Div/µs

≥ 200 Div/µs

REV. Original DATE 6-1-73

SEC. II - CONTROL PROCEDURE

PAGE 12 of 16

CONTROL PROCEDURE FOR T7411 TESTING

A. INTRODUCTION

T7411 testing is under control if electrode voltages, and erase, prep, and transfer waveforms are within specifications. Monitoring of these voltage and waveforms must be done with calibrated equipment at various prescribed intervals. Test control evaluation is provided by periodic testing of "standard" tubes.

B. PARAMETERS TO BE MONITORED

Parameter Sample Rate		Specification	Control Limit		
2 V			W/O Gearshift	Gearshift	
1. Test set mor calibration.	_	twice/period			e e e e e e e e e e e e e e e e e e e
a. DVM					
Current			< 1%		< 1%
Voltage	4		<1%		< 1%
2. Operating Voltages: (DC) (Respect to Gnd.)					
WG-Htr		twice/period	6.3V ± 10% across heaters	-3000	Same as Spec.
WG-K		twice/period	-1475 ± 15V	-3000 ± 30V	Same as Spec.
WG-Grid		twice/period	-1580 to -1500V	-3105 to -3025V	Same as Spec.
Tetrode	Wafer	twice/period	+25 ± 1V	-1500 ± 15V	Same as Spec.
WG-Anod D3D4 Sh		twice/period	25 ± 1V	25 ± 1V	Same as Spec.
WG-Focu	LS	twice/period	-825 to -1235V	-2150 to -2450V	Same as Spec.
D3D4 P1	ate Ave.	twice/period	25 ± 2V	25 ± 2V	Same as Spec.
D1D2 P1	ate Ave.	twice/period	42 ± 2V	42 ± 2V	Same as Spec.
Isolati Shield		twice/period	-40 ± 1V	-130 ± 25V	Same as Spec.
Astigma (2nd An		twice/period	-15 to 100V	45 to 130V	Same as Spec.
Geometr (D1D2 S		twice/period	-15 to 95V	-15 to 95V	Same as Spec.
FG-Htr		twice/period	12.6V across heaters	12.6V across heaters	Same as Spec.
FGK	American State of the State of	daily	0 ± .1V (store) 50V ± 2V (modes)	0 ± .1V (store) 50V ± 2V (modes)	ov

(Non-store)

(Non-store)

Same as Spec.

REV. Original DATE 6-1-73

SEC. II - CONTROL PROCEDURES (Cont.)

CONTROL PROCEDURE FOR T7411 TESTING (Cont.)

PAGE 13 of 16

B. PARAMETERS TO BE MONITORED (Cont.)

	1				
Pa	rameter	Sample Rate	Specification	n Limit	Control Limit
			W/O Gearshift	Gearshift	
2.	Operating Voltages: (DC) (Respect to Gr				
	Screen	twice/period	7000 ± 70V (Non-store)	7000 ± 70V (Non-store)	Same as Spec.
3.	Waveforms		Specification	Limit	
	I. Bistable Mode	Weekly	± 2%		± 1%
, a , /	II. Transfer Mode	Weekly	± 2%		± 1%
	III Halftone Mode	Weekly	± 2%		± 1%
	IV. Non-Store Mode	Weekly	± 2%		± 1%
4.	Standard Tubes	1 tube/wk/shif	t Ea. perform. parameter within control limits on tube card.		Same as Spec. Limit

C. SAMPLING PLAN

During the first and third week of each period, the test set should be calibrated for current and voltage monitoring. At the same time, the electrode voltages, except storage, should be checked and reset. First tube to be tested each day should be used in checking Storage and High-Speed electrode voltages. Erase and prep waveforms, and non-store waveforms need to be evaluated once each week (at the beginning of the week).

Standard tubes should be checked at a rate of one (1) per week/shift (at the beginning of the week). Standard tube test results should be within the control limits on the tube card. If not, check test set before testing tubes.

All control criteria need evaluation after a major test-set breakdown and repair.

01 11-14-73 14 of 16 REV. DATE V000 2M66b 1500+ 2M66b 1100+ 1000 TRANSFER HALFTONE 72.5V LA SPACE 65V 132.5V 009 520 10 ms per Mar and 125V 8 700 747 -001 **4009** 20 30 0 65 45 100 . 009 132.5V HALFTONE 8 45V 65V 125V 520 747 700 **600V** 00 T 20 00 31 210 0 BISTABLE TRANSFER 65V Sweep 1 **9009** 1100+ 2meeb 20V 300 128V 45V 200 T000+ -009 10 ms per 100 0 125V 517 **SPAR** 85V 85V **MO6** 85V **6000** T00 150 -0 36 45 T7411 STORAGE WAV 35 400 364 200 450 BISTABLE -009 3 85V 125V 1150 567 90V 857 850 **600V** 100 -0 NON-STORE 387 707 36V -15V 150V 125V 450 V50 600V 100 8 0 0.1 MODE FLOOD GUN TIME (ms) FLOOD GUN COLLECTOR HI-SPEED STORAGE ANODE C S CE MESH CES MESH HSZW ELEPTINI

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NO.

8-2019

D.	CORRECTIVE ACTIO	<u>N</u>		PAGE 15 of 16
	PARAMETER	PROBLEM	POSSIBLE CAUSE	CORRECTIVE ACTION
	BISTABLE MODE 1. Storage	No storage	Open leads or improper connections	Re-solder all leads and check connections.
			Open internal leads.	Reject tube.
			Storage circuitry failure	Check test set; repair if necessary.
	2. Erase	No erase	Same as no storage	Same as no storage
		Poor erase	Waveforms out 'of calibration	Calibrate; repair if necessary.
	TRANSFER MODE			
	1. Storage	No storage	Same as Bistable Mode	Same as Bistable Mode.
	2. Prep	No prep	No prep pulse; storage circuitry malfunction.	Check test set; repair if necessary.
	3. Waiting	Hangs up in prep	Equipment mal- function	Check test set; repair if necessary.
R			Timebase not triggered.	Rotate trigger knob.
R	4. Transfer	No transfer or 100% transfer	V _t and V _p not correct	Re-adjust and try again.
			Sweep too fast or too slow.	Re-adjust and try again.
			Equipment mal- function	Check test set; repair.
	5. Erase	No erase	Same as Bistable Mode	Same as Bistable Mode
		Poor erase	Same as Bistable Mode	Same as Bistable Mode
R	6. Stability	Target not stable	V _p not correct.	Adjust and try again.
			Equipment mal- function	Check test set; repair if necessary.

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REV. DATE